

# CEH2351

**-150V ▲ 560mΩ ▲ -1.45A ▲ Si MOSFET**

SILICON Si MOSFET ▲ SMD type  
 P-channel enhancement mode  
 UL94V-0 rated flame retardant epoxy  
 TSOP6 package ▲ MSL 3

Super high dense cell density for extremely low  $R_{DS(ON)}$   
**High power and current handling capability**

## MAXIMUM RATINGS

Parameter ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)		Characteristics
Drain-Source Voltage	$V_{DS}$	-150V
Gate-Source Voltage	$V_{GS}$	$\pm 20\text{V}$
Continuous Drain Current at $R_{TH\_JL}$	$I_D$	-1.45A
Continuous Drain Current at $R_{TH\_JA}$	$I_D$	-1.15A
Pulsed Drain Current at $R_{TH\_JL}$ <sup>Note 1</sup>	$I_{DM}$	-5.8A
Pulsed Drain Current at $R_{TH\_JA}$ <sup>Note 1</sup>	$I_{DM}$	-4.6A
Maximum Power Dissipation	$P_D$	2W
Operating and Storage Temperature Range	$T_J, T_{STG}$	$-55^\circ\text{C}$ to $+150^\circ\text{C}$

## THERMAL CHARACTERISTICS

Parameter	Symbol	Limit
Thermal Resistance, Junction-to-Ambient <sup>Note 2</sup>	$R_{TH\_JA}$	$62.5^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Lead	$R_{TH\_JL}$	$40^\circ\text{C}/\text{W}$

## APPLICATIONS

CCTV	Large Displays	Pico Cells	Power over Ethernet	WIFI Hotspots

## PIN DESCRIPTION

Circuit Diagram	Outline - Bottom View	Pin No.	Description
		1 2 3 4 5 6	Drain Drain Gate Source Drain Drain

**ELECTRICAL CHARACTERISTICS ▲  $T_A = 25^\circ\text{C}$ , unless otherwise noted**

Item	Condition	Symbol	Min.	Typ.	Max.	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{V}, I_D = -250\mu\text{A}$	$BV_{DSS}$	-150			V
Zero Gate Voltage Drain Current	$V_{DS} = -150\text{V}, V_{GS} = 0\text{V}$	$I_{DSS}$			-1	$\mu\text{A}$
Gate Body Leakage Current, Forward	$V_{GS} = 20\text{V}, V_{DS} = 0\text{V}$	$I_{GSSF}$			100	nA
Gate Body Leakage Current, Reverse	$V_{GS} = -20\text{V}, V_{DS} = 0\text{V}$	$I_{GSSR}$			-100	nA
<b>On Characteristics</b> <sup>Note 3</sup>						
Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = -250\mu\text{A}$	$V_{GS(th)}$	-2		-4	V
Static Drain-Source On-Resistance	$V_{GS} = -10\text{V}, I_D = -1.4\text{A}$	$R_{DS(ON)}$		560	720	m $\Omega$
Static Drain-Source On-Resistance	$V_{GS} = -6\text{V}, I_D = -1\text{A}$	$R_{DS(ON)}$		590	750	m $\Omega$
<b>Dynamic Characteristics</b> <sup>Note 4</sup>						
Input Capacitance	$V_{DS} = -50\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$	$C_{ISS}$		770		pF
Output Capacitance	$V_{DS} = -50\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$	$C_{OSS}$		55		pF
Reverse Transfer Capacitance	$V_{DS} = -50\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$	$C_{RSS}$		30		pF
<b>Switching Characteristics</b> <sup>Note 4</sup>						
Turn-On Delay Time	$V_{DD} = -75\text{V}, V_{GS} = -10\text{V}, I_D = -1\text{A}, R_{G(ext)} = 1\Omega$	$t_{D(ON)}$		15		ns
Turn-On Rise Time	$V_{DD} = -75\text{V}, V_{GS} = -10\text{V}, I_D = -1\text{A}, R_{G(ext)} = 1\Omega$	$t_R$		5		ns
Turn-Off Delay Time	$V_{DD} = -75\text{V}, V_{GS} = -10\text{V}, I_D = -1\text{A}, R_{G(ext)} = 1\Omega$	$t_{D(OFF)}$		33		ns
Turn-Off Fall Time	$V_{DD} = -75\text{V}, V_{GS} = -10\text{V}, I_D = -1\text{A}, R_{G(ext)} = 1\Omega$	$t_F$		3		ns
Total Gate Charge	$V_{DS} = -75\text{V}, V_{GS} = -6\text{V}, I_D = -1\text{A}$	$Q_G$		11		nC
Gate Source Charge	$V_{DS} = -75\text{V}, V_{GS} = -6\text{V}, I_D = -1\text{A}$	$Q_{GS}$		2		nC
Gate Drain Charge	$V_{DS} = -75\text{V}, V_{GS} = -6\text{V}, I_D = -1\text{A}$	$Q_{GD}$		5		nC
<b>Drain-Source Diode Characteristics and Maximum Ratings</b>						
Drain-Source Diode Forward Current <sup>Note 2</sup>		$I_S$			-1.4	A
Drain-Source Diode Forward Voltage <sup>Note 3</sup>	$V_{GS} = 0\text{V}, I_S = -1.4\text{A}$	$V_{SD}$			-1.2	V

**Notes**

- 1: Repetitive Rating: Pulse width limited by maximum junction temperature
- 2: Surface Mounted on FR4 Board,  $t \leq 5$  sec.
- 3: Pulse Test: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 2\%$ .
- 4: Guaranteed by design, not subject to production testing.

## REFERENCE DATA ▲ TYPICAL DEVICE PERFORMANCE

Fig. 1 • Output Characteristics

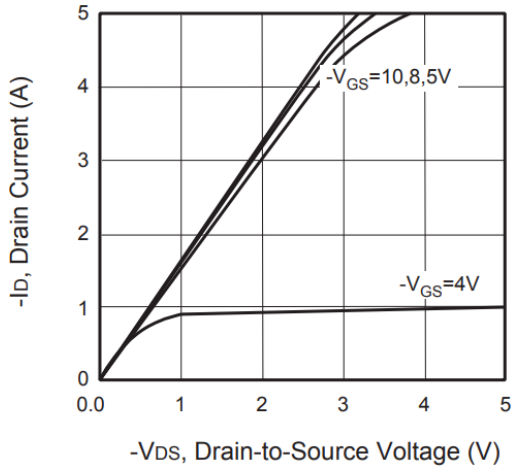


Fig. 2 • Transfer Characteristics

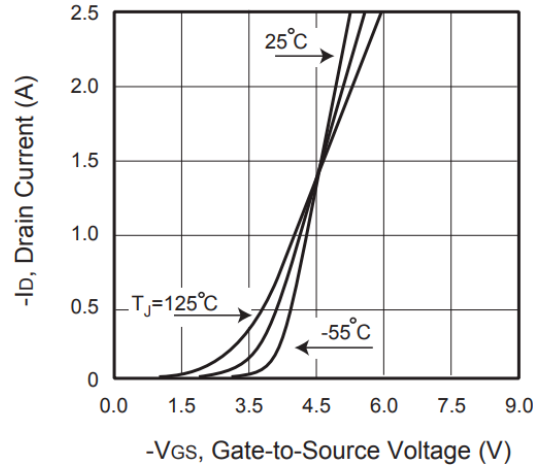


Fig. 3 • Capacitance

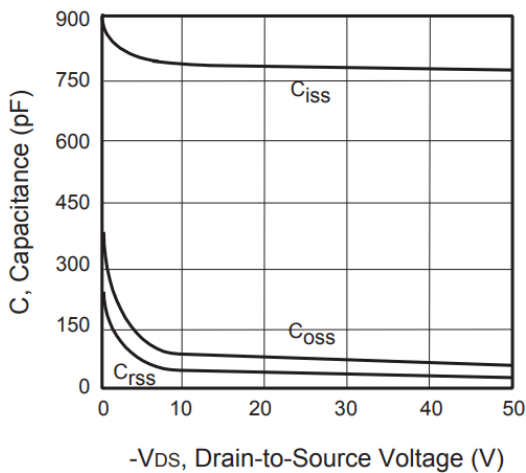


Fig. 4 • On-Resistance Variation with Temperature

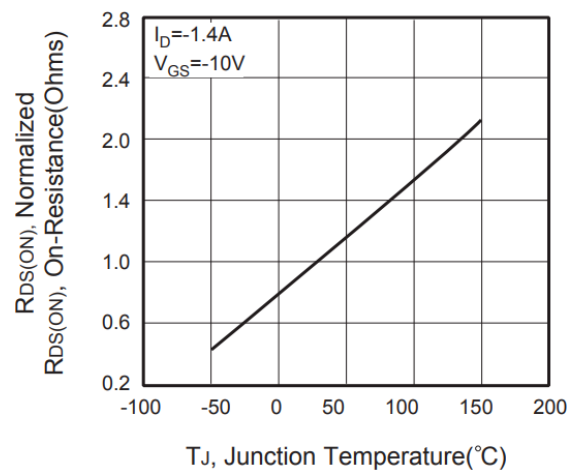


Fig. 5 • Gate Threshold Variation with Temperature

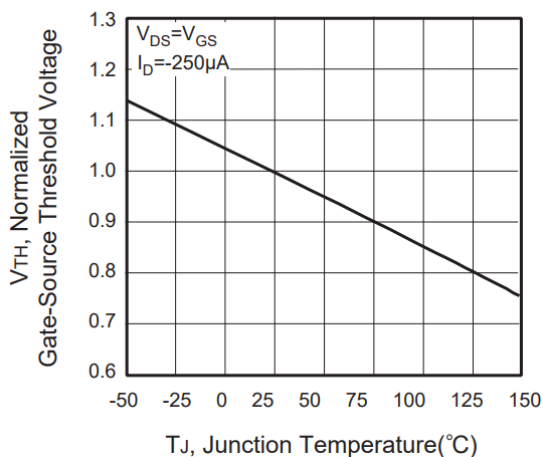
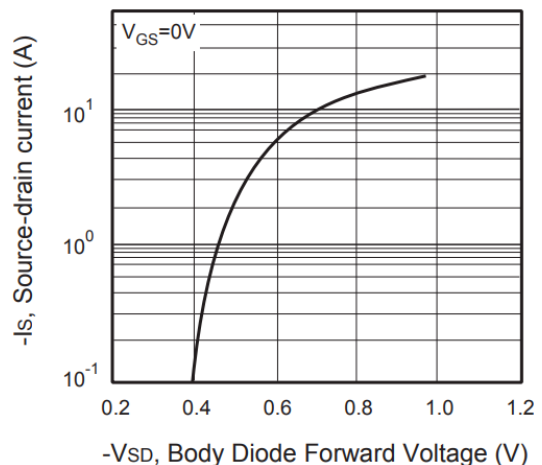


Fig. 6 • Body Diode Forward Voltage Variation with Source Current



REFERENCE DATA ▲ TYPICAL DEVICE PERFORMANCE

Fig. 7 • Gate Charge

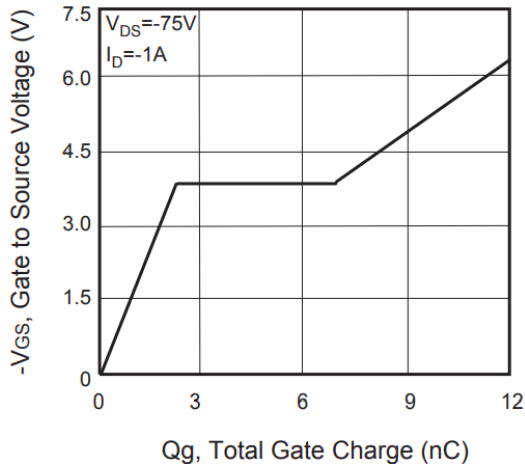


Fig. 8 • Maximum Safe Operating Area

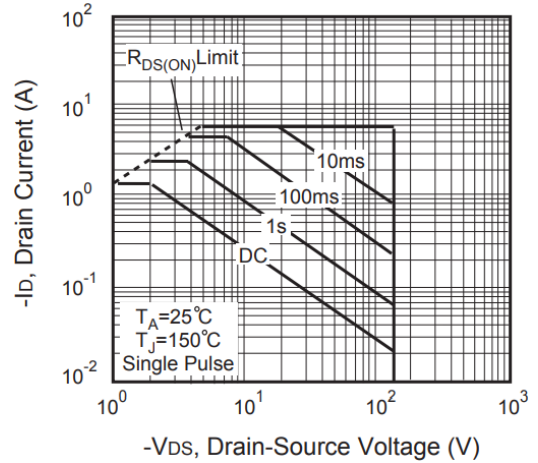


Fig. 9 • Switching Test Circuit

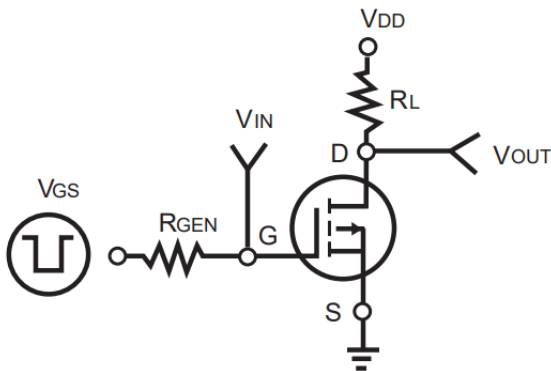


Fig. 10 • Switching Waveforms

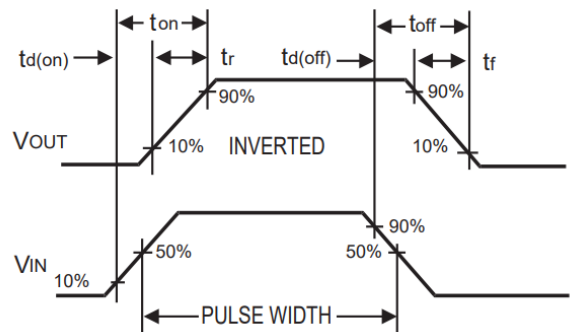
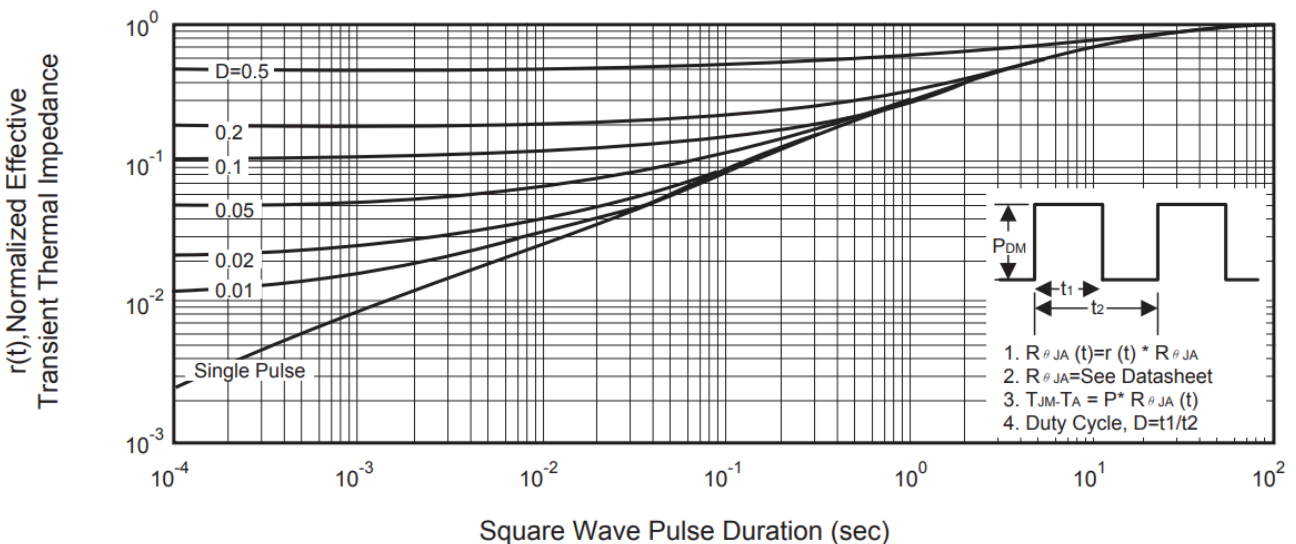
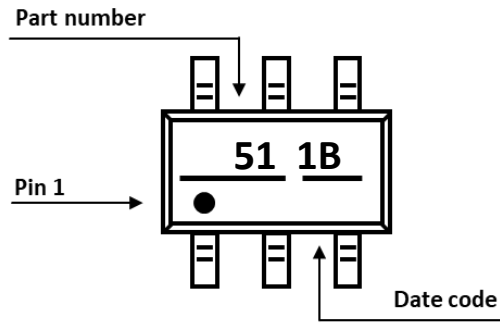


Fig. 11 • Normalized Thermal Transient Impedance Curve

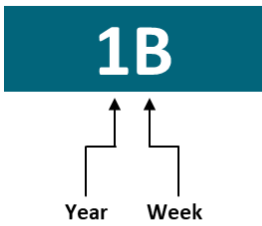


## PART MARKING



## DATE CODE

Example: 1B

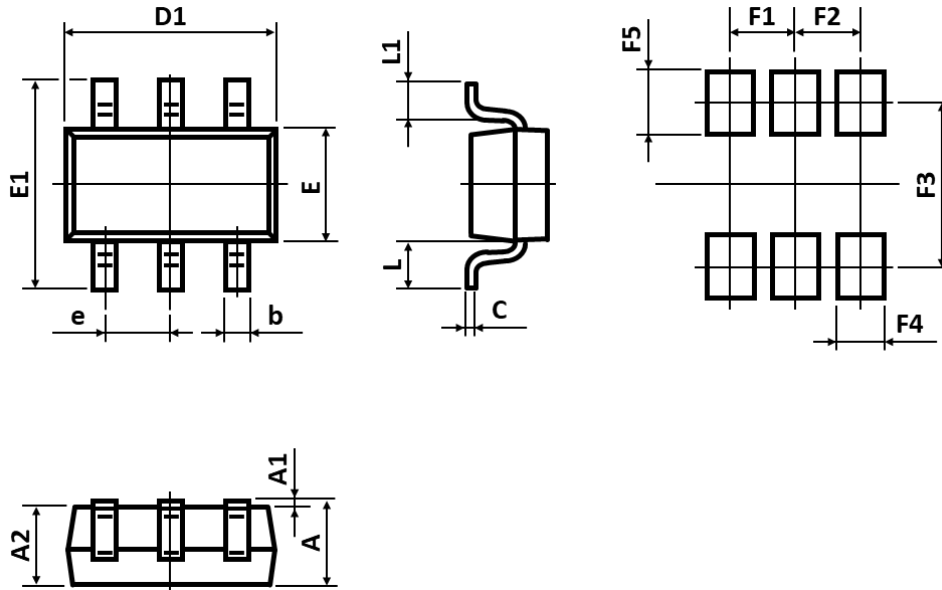


Coding list for „Week“

<b>A</b>	<b>B</b>	<b>C</b>	<b>D</b>	<b>E</b>	<b>F</b>	<b>G</b>	<b>H</b>	<b>I</b>
1-2	3-4	5-6	7-8	9-10	11-12	13-14	15-16	17-18
<b>J</b>	<b>K</b>	<b>L</b>	<b>M</b>	<b>N</b>	<b>O</b>	<b>P</b>	<b>Q</b>	<b>R</b>
19-20	21-22	23-24	25-26	27-28	29-30	31-32	33-34	35-36
<b>S</b>	<b>T</b>	<b>U</b>	<b>V</b>	<b>W</b>	<b>X</b>	<b>Y</b>	<b>Z</b>	
37-38	39-40	41-42	43-44	45-46	47-48	49-50	51-52	

Coding list for „Year“

<b>0</b>	<b>1</b>	<b>2</b>	<b>3</b>	<b>4</b>
2020	2021	2022	2023	2024
<b>5</b>	<b>6</b>	<b>7</b>	<b>8</b>	<b>9</b>
2025	2026	2027	2028	2029

**PACKAGE OUTLINE AND RECOMMENDED PAD LAYOUT**


Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
A	0.800	-	1.250
A1	0.000	-	0.130
A2	0.700	-	1.200
b	0.300	-	0.500
C	0.090	-	0.200
D1	2.800	-	3.100

Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
E	1.500	-	1.700
E1	2.500	-	3.100
e	0.950 (TYP)		
L	0.350	-	0.800
L1	0.300	-	0.550

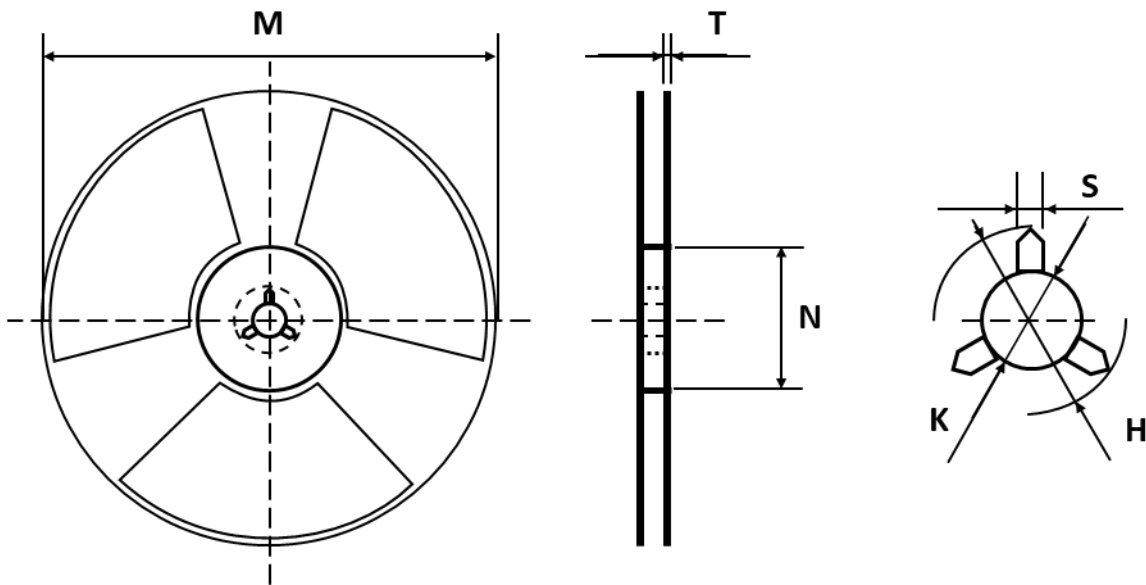
Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
F1	-	0.950	-
F2	-	0.950	-
F3	-	2.600	-

Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
F4	-	0.700	-
F5	-	1.000	-

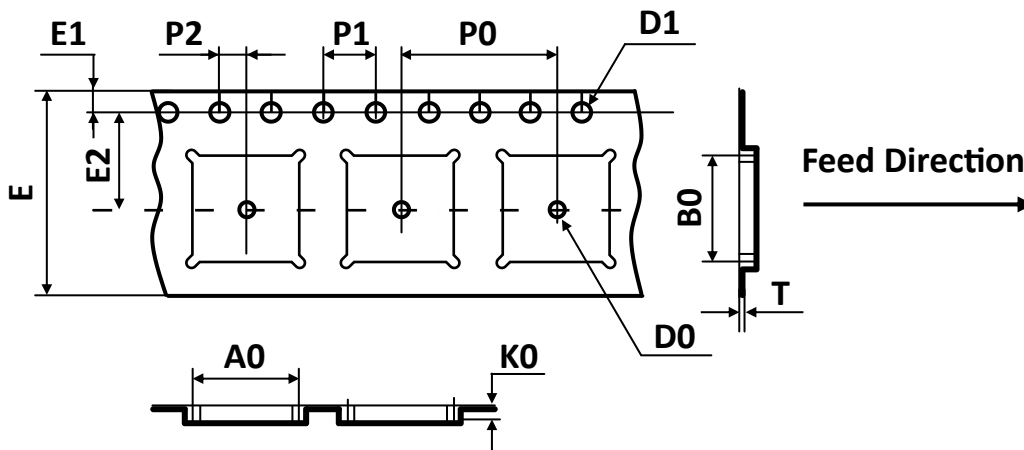
- Notes: 1. The suggested land pattern dimensions have been provided for reference only.  
 2. For further information, please reference document IPC-7351A.

**ORDERING INFORMATION**

Part Number	Package	Packing	Reel Qty.	Inner Box Qty.
CEH2351	TSOP 6	Reel	3,000pcs	15,000pcs

**REEL DIMENSIONS ▲ All dimensions in mm**


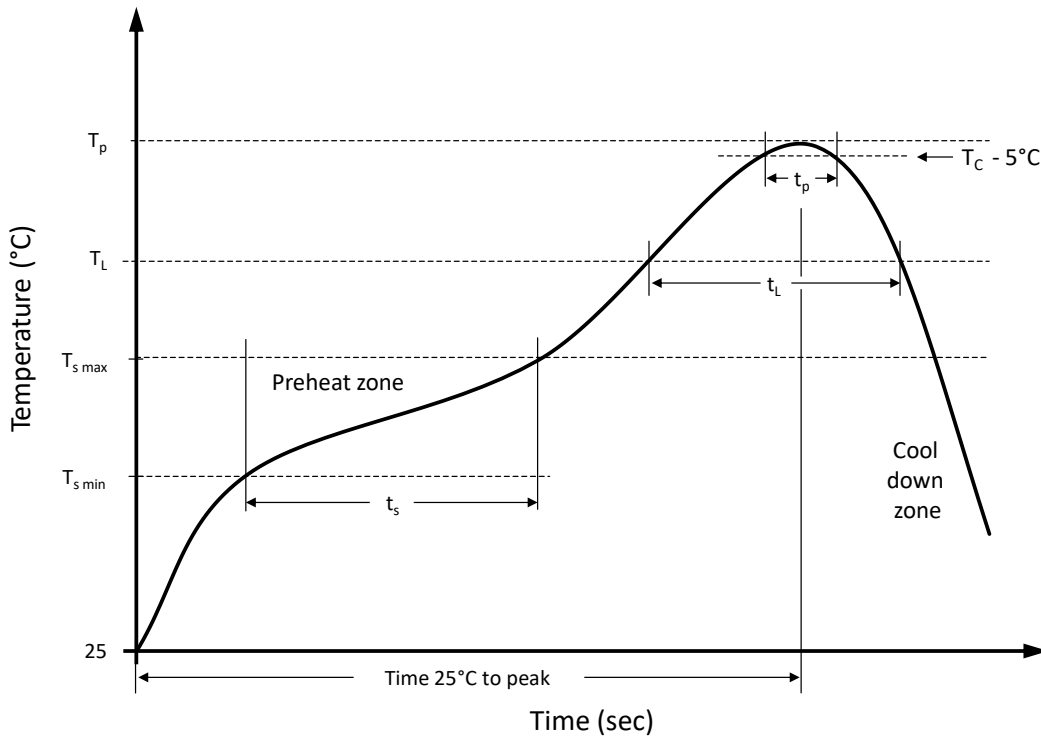
Tape Size	Reel Size	M	N	T	H	K	S
8mm	Ø180	Ø178.00	Ø54.00	1.20	20.00	13.30	3.00
		±1.00	±0.50	±0.20	±1.00	±0.30	±1.00

**TAPE DIMENSIONS ▲ All dimensions in mm**


Package	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
TSOP6	3.20	3.20	1.35	1.00	1.50	8.00	1.75	3.50	4.00	4.00	2.00	0.20
	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.05	±0.02

**Note:** All dimensions meet EIA-481-D requirements.

## RECOMMENDED REFLOW SOLDERING PROFILE



### Recommended reflow soldering conditions ▲ Refer to JEDEC J-STD-020E

Profile Features		Sn-Pb Eutetic Assembly	Pb-Free Assembly
Preheat temperature min.	$T_{s \text{ min}}$	100 °C	150 °C
Preheat temperature max.	$T_{s \text{ max}}$	150 °C	200 °C
Preheat time $t_s$ from $T_{s \text{ min}}$ to $T_{s \text{ max}}$	$t_s$	120 seconds	120 seconds
Ramp-up rate ( $T_L$ to $T_p$ )		max. 3 °C/second	max. 3 °C/second
Liquidous temperature	$T_L$	183 °C	217 °C
Time $t_L$ maintained above $T_L$	$t_L$	150 seconds max.	150 seconds max.
Peak package body temperature	$T_p$	235°C	260°C
Timeframe of within 5°C below and up to max actual peak body temperature	$t_p$	20 seconds max.	30 seconds max.
Ramp-down rate ( $T_L$ to $T_p$ )		max. 6 °C/second	max. 6 °C/second
Time 25°C to peak temperature		max. 6 minutes	max. 8 minutes



## REVISION TABLE

Revision	Date	Status	Notes
001	30/09/2022	Initial release	Initial publication

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